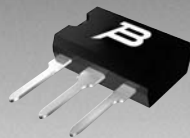


*RoHS COMPLIANT



BOURNS®

**TISP3070H3SL THRU TISP3115H3SL,
TISP3125H3SL THRU TISP3210H3SL,
TISP3250H3SL THRU TISP3350H3SL**

DUAL BIDIRECTIONAL THYRISTOR OVERVOLTAGE PROTECTORS

TISP3xxxH3SL Overvoltage Protector Series

TISP3xxxH3SL Overview

This TISP® device series protects central office, access and customer premise equipment against overvoltages on the telecom line. The TISP3xxxH3SL protects R-G and T-G. In addition, the device is rated for simultaneous R-G and T-G impulse conditions. The TISP3xxxH3SL is available in a wide range of voltages and has a high current capability, allowing minimal series resistance to be used. These protectors have been specified mindful of the following standards and recommendations: GR-1089-CORE, FCC Part 68, UL1950, EN 60950, IEC 60950, ITU-T K.20, K.21 and K.45. The TISP3350H3SL meets the FCC Part 68 "B" ringer voltage requirement and survives both Type A and B impulse tests. These devices are housed in a through-hole 3-pin single-in-line (SL) plastic package.

Summary Electrical Characteristics

| Part # | V _{DRM} V | V _(BO) V | V _T @ I _T V | I _{DRM} μA | I _(BO) mA | I _T A | I _H mA | C _o @ -2 V pF | Functionally Replaces |
|------------|-----------------------|------------------------|--------------------------------------|------------------------|-------------------------|---------------------|----------------------|-----------------------------|--------------------------|
| TISP3070H3 | 58 | 70 | 3 | 5 | 600 | 5 | 150 | 140 | P1402AC† |
| TISP3080H3 | 65 | 80 | 3 | 5 | 600 | 5 | 150 | 140 | P1602AC† |
| TISP3095H3 | 75 | 95 | 3 | 5 | 600 | 5 | 150 | 140 | |
| TISP3115H3 | 90 | 115 | 3 | 5 | 600 | 5 | 150 | 74 | P2202AC† |
| TISP3125H3 | 100 | 125 | 3 | 5 | 600 | 5 | 150 | 74 | |
| TISP3135H3 | 110 | 135 | 3 | 5 | 600 | 5 | 150 | 74 | |
| TISP3145H3 | 120 | 145 | 3 | 5 | 600 | 5 | 150 | 74 | P2702AC† |
| TISP3180H3 | 145 | 180 | 3 | 5 | 600 | 5 | 150 | 74 | P3002AC |
| TISP3210H3 | 160 | 210 | 3 | 5 | 600 | 5 | 150 | 74 | P3602AC† |
| TISP3250H3 | 190 | 250 | 3 | 5 | 600 | 5 | 150 | 62 | P4202AC |
| TISP3290H3 | 220 | 290 | 3 | 5 | 600 | 5 | 150 | 62 | P4802AC† |
| TISP3350H3 | 275 | 350 | 3 | 5 | 600 | 5 | 150 | 62 | P6002AC |

† Bourns part has an improved protection voltage

Summary Current Ratings

| Parameter | I _{TSP} A | | | | | | I _{TSM} A | di/dt A/μs |
|-----------|-----------------------|--------------|--------|-------|--------|---------|-----------------------|----------------|
| | 2/10 | 1.2/50, 8/20 | 10/160 | 5/320 | 10/560 | 10/1000 | | |
| Waveshape | 2/10 | 1.2/50, 8/20 | 10/160 | 5/320 | 10/560 | 10/1000 | 1 cycle 60 Hz | 2/10 Wavefront |
| Value | 500 | 300 | 250 | 200 | 130 | 100 | 60 | 400 |

*RoHS Directive 2002/95/EC Jan 27 2003 including Annex
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Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

TISP3xxxH3SL Overvoltage Protector Series

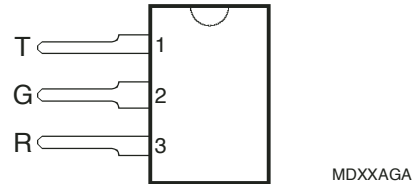


ITU-T K.20/21 Rating 8 kV 10/700, 200 A 5/310

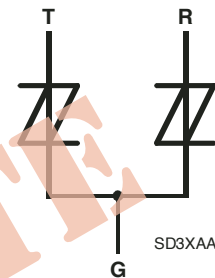
Ion-Implanted Breakdown Region
Precise and Stable Voltage
Low Voltage Overshoot under Surge

| Device | V _{DRM} V | V _(BO) V |
|--------|-----------------------|------------------------|
| '3070 | 58 | 70 |
| '3080 | 65 | 80 |
| '3095 | 75 | 95 |
| '3115 | 90 | 115 |
| '3125 | 100 | 125 |
| '3135 | 110 | 135 |
| '3145 | 120 | 145 |
| '3180 | 145 | 180 |
| '3210 | 160 | 210 |
| '3250 | 190 | 250 |
| '3290 | 220 | 290 |
| '3350 | 275 | 350 |

SL Package (Top View)



Device Symbol



Terminals T, R and G correspond to the alternative line designators of A, B and C

Rated for International Surge Wave Shapes - Single and Simultaneous Impulses

| Waveshape | Standard | I _{TSP} A |
|------------|------------------------------|-----------------------|
| 2/10 μs | GR-1089-CORE | 500 |
| 8/20 μs | IEC 61000-4-5 | 300 |
| 10/160 μs | FCC Part 68 | 250 |
| 10/700 μs | FCC Part 68 ITU-T K.20/21 | 200 |
| 10/560 μs | FCC Part 68 | 160 |
| 10/1000 μs | GR-1089-CORE | 100 |

3-Pin Through-Hole Packaging

- Compatible with TO-220AB pin-out
- Low Height.....8.3 mm

Low Differential Capacitance.....< 67 pF

.....UL Recognized Component

Description

The TISP3xxxH3SL limits overvoltages between the telephone line Ring and Tip conductors and Ground. Overvoltages are normally caused by a.c. power system or lightning flash disturbances which are induced or conducted on to the telephone line.

The protector consists of two symmetrical voltage-triggered bidirectional thyristors. Overvoltages are initially clipped by breakdown clamping until the voltage rises to the breakover level, which causes the device to crowbar into a low-voltage on state. This low-voltage on state causes the current resulting from the overvoltage to be safely diverted through the device. The high crowbar holding current helps prevent d.c. latchup as the diverted current subsides.

How To Order

| Device | Package | Carrier | Order As |
|------------|---------------------|---------|----------------|
| TISP3xxxH3 | SL (Single-in-Line) | Tube | TISP3xxxH3SL-S |

Insert xxx value corresponding to protection voltages of 070, 080, 095, 115 etc.

This TISP3xxxH3SL range consists of twelve voltage variants to meet various maximum system voltage levels (58 V to 275 V). They are guaranteed to voltage limit and withstand the listed international lightning surges in both polarities. These high current protection devices are in a 3-pin single-in-line (SL) plastic package and are supplied in tube pack. For alternative impulse rating, voltage and holding current values in SL packaged protectors, consult the factory. For lower rated impulse currents in the SL package, the 35 A 10/1000 TISP3xxxH3F3SL series is available. These monolithic protection devices are fabricated in ion-implanted planar structures to ensure precise and matched breakover control and are virtually transparent to the system in normal operation.

TISP3xxxH3SL Overvoltage Protector Series

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Absolute Maximum Ratings, $T_A = 25\text{ }^\circ\text{C}$ (Unless Otherwise Noted)

| Rating | Symbol | Value | Unit | |
|---|-----------|-------------|--|-----|
| Repetitive peak off-state voltage, (see Note 1) | '3070 | ± 58 | V | |
| | '3080 | ± 65 | | |
| | '3095 | ± 75 | | |
| | '3115 | ±90 | | |
| | '3125 | ±100 | | |
| | '3135 | ±110 | | |
| | '3145 | ±120 | | |
| | '3180 | ±145 | | |
| | '3210 | ±160 | | |
| | '3250 | ±190 | | |
| | '3290 | ±220 | | |
| | '3350 | ±275 | | |
| Non-repetitive peak on-state pulse current (see Notes 2, 3 and 4) | I_{TSP} | A | 2/10 μs (GR-1089-CORE, 2/10 μs voltage wave shape) | 500 |
| 8/20 μs (IEC 61000-4-5, 1.2/50 μs voltage, 8/20 current combination wave generator) | | | 300 | |
| 10/160 μs (FCC Part 68, 10/160 μs voltage wave shape) | | | 250 | |
| 5/200 μs (VDE 0433, 10/700 μs voltage wave shape) | | | 220 | |
| 0.2/310 μs (I3124, 0.5/700 μs voltage wave shape) | | | 200 | |
| 5/310 μs (ITU-T K.20/21, 10/700 μs voltage wave shape) | | | 200 | |
| 5/310 μs (FTZ R12, 10/700 μs voltage wave shape) | | | 200 | |
| 5/320 μs (FCC Part 68, 9/720 μs voltage wave shape) | | | 200 | |
| 10/560 μs (FCC Part 68, 10/560 μs voltage wave shape) | | | 160 | |
| 10/1000 μs (GR-1089-CORE, 10/1000 μs voltage wave shape) | | | 100 | |
| Non-repetitive peak on-state current (see Notes 2, 3 and 5) | I_{TSM} | A | 20 ms (50 Hz) full sine wave | 55 |
| 16.7 ms (60 Hz) full sine wave | | | 60 | |
| 1000 s 50 Hz/60 Hz a.c. | | | 1 | |
| Initial rate of rise of on-state current, Exponential current ramp, Maximum ramp value < 200 A | di_T/dt | 400 | A/ μs | |
| Junction temperature | T_J | -40 to +150 | $^\circ\text{C}$ | |
| Storage temperature range | T_{stg} | -65 to +150 | $^\circ\text{C}$ | |

- NOTES: 1. See Figure 9 for voltage values at lower temperatures.
 2. Initially the TISP3xxxH3SL must be in thermal equilibrium.
 3. These non-repetitive rated currents are peak values of either polarity. The rated current values may be applied to the R or T terminals. Additionally, both R and T terminals may have their rated current values applied simultaneously (in this case the G terminal return current will be the sum of the currents applied to the R and T terminals). The surge may be repeated after the TISP3xxxH3SL returns to its initial conditions.
 4. See Figure 10 for impulse current ratings at other temperatures. Above 85 $^\circ\text{C}$, derate linearly to zero at 150 $^\circ\text{C}$ lead temperature.
 5. EIA/JESD51-2 environment and EIA/JESD51-3 PCB with standard footprint dimensions connected with 5 A rated printed wiring track widths. See Figure 8 for the current ratings at other durations. Figure 8 shows the R and T terminal current rating for simultaneous operation. In this condition, the G terminal current will be $2xI_{TSM(t)}$, the sum of the R and T terminal currents. Derate current values at $-0.61\text{ }^\circ\text{C}$ for ambient temperatures above 25 $^\circ\text{C}$.

TISP3xxxH3SL Overvoltage Protector Series

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Electrical Characteristics for the R and G or T and G Terminals, $T_A = 25\text{ °C}$ (Unless Otherwise Noted)

| Parameter | Test Conditions | Min | Typ | Max | Unit |
|--|--|------------|-----|---|------------|
| I_{DRM} Repetitive peak off-state current | $V_D = V_{DRM}$ $T_A = 25\text{ °C}$ $T_A = 85\text{ °C}$ | | | ± 5 ± 10 | μA |
| $V_{(BO)}$ Breakover voltage | $dv/dt = \pm 750\text{ V/ms}$, $R_{SOURCE} = 300\ \Omega$ | | | '3070 ± 70 '3080 ± 80 '3095 ± 95 '3115 ± 115 '3125 ± 125 '3135 ± 135 '3145 ± 145 '3180 ± 180 '3210 ± 210 '3250 ± 250 '3290 ± 290 '3350 ± 350 | V |
| $V_{(BO)}$ Impulse breakover voltage | $dv/dt \leq 1000\text{ V}/\mu s$, Linear voltage ramp, Maximum ramp value = $\pm 500\text{ V}$ $di/dt = \pm 20\text{ A}/\mu s$, Linear current ramp, Maximum ramp value = $\pm 10\text{ A}$ | | | '3070 ± 78 '3080 ± 88 '3095 ± 103 '3115 ± 124 '3125 ± 134 '3135 ± 144 '3145 ± 154 '3180 ± 189 '3210 ± 220 '3250 ± 261 '3290 ± 302 '3350 ± 362 | V |
| $I_{(BO)}$ Breakover current | $dv/dt = \pm 750\text{ V/ms}$, $R_{SOURCE} = 300\ \Omega$ | ± 0.15 | | ± 0.6 | A |
| V_T On-state voltage | $I_T = \pm 5\text{ A}$, $t_W = 100\ \mu s$ | | | ± 3 | V |
| I_H Holding current | $I_T = \pm 5\text{ A}$, $di/dt = -/+30\text{ mA/ms}$ | ± 0.15 | | ± 0.6 | A |
| dv/dt Critical rate of rise of off-state voltage | Linear voltage ramp, Maximum ramp value $< 0.85V_{DRM}$ | ± 5 | | | $kV/\mu s$ |
| I_D Off-state current | $V_D = \pm 50\text{ V}$ $T_A = 85\text{ °C}$ | | | ± 10 | μA |
| C_{off} Off-state capacitance | $f = 100\text{ kHz}$, $V_d = 1\text{ V rms}$, $V_D = 0$, $f = 100\text{ kHz}$, $V_d = 1\text{ V rms}$, $V_D = -1\text{ V}$, $f = 100\text{ kHz}$, $V_d = 1\text{ V rms}$, $V_D = -2\text{ V}$, $f = 100\text{ kHz}$, $V_d = 1\text{ V rms}$, $V_D = -50\text{ V}$, $f = 100\text{ kHz}$, $V_d = 1\text{ V rms}$, $V_D = -100\text{ V}$ (see Note 6) | | | '3070 thru '3115 170 '3125 thru '3210 90 '3250 thru '3350 84 '3070 thru '3115 150 '3125 thru '3210 79 '3250 thru '3350 67 '3070 thru '3115 140 '3125 thru '3210 74 '3250 thru '3350 62 '3070 thru '3115 73 '3125 thru '3210 35 '3250 thru '3350 28 '3125 thru '3210 33 '3250 thru '3350 26 | pF |

NOTE 6: To avoid possible voltage clipping, the '3125 is tested with $V_D = -98\text{ V}$.

TISP3xxxH3SL Overvoltage Protector Series

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Electrical Characteristics for the R and T Terminals, $T_A = 25\text{ }^\circ\text{C}$ (Unless Otherwise Noted)

| Parameter | Test Conditions | Min | Typ | Max | Unit |
|---|--|-----------|-----|-----------|---------------|
| I_{DRM} Repetitive peak off-state current | $V_D = 2V_{DRM}$ | | | ± 5 | μA |
| $V_{(BO)}$ Breakover voltage | $dv/dt = \pm 750\text{ V/ms}$, $R_{SOURCE} = 300\ \Omega$ | '3070 | | ± 140 | V |
| | | '3080 | | ± 160 | |
| | | '3095 | | ± 190 | |
| | | '3115 | | ± 230 | |
| | | '3125 | | ± 250 | |
| | | '3135 | | ± 270 | |
| | | '3145 | | ± 290 | |
| | | '3180 | | ± 360 | |
| | | '3210 | | ± 420 | |
| | | '3250 | | ± 500 | |
| $V_{(BO)}$ Impulse breakover voltage | $dv/dt \leq \pm 1000\text{ V}/\mu\text{s}$, Linear voltage ramp, Maximum ramp value = $\pm 500\text{ V}$, $di/dt = \pm 20\text{ A}/\mu\text{s}$, Linear current ramp, Maximum ramp value = $\pm 10\text{ A}$ | '3070 | | ± 156 | V |
| | | '3080 | | ± 176 | |
| | | '3095 | | ± 206 | |
| | | '3115 | | ± 248 | |
| | | '3125 | | ± 268 | |
| | | '3135 | | ± 288 | |
| | | '3145 | | ± 308 | |
| | | '3180 | | ± 378 | |
| | | '3210 | | ± 440 | |
| | | '3250 | | ± 522 | |
| '3290 | | ± 604 | | | |
| '3350 | | ± 724 | | | |

Thermal Characteristics

| Parameter | Test Conditions | Min | Typ | Max | Unit |
|---|--|-----|-----|-----|---------------------------|
| $R_{\theta JA}$ Junction to free air thermal resistance | EIA/JESD51-3 PCB, $I_T = I_{TSM(1000)}$, $T_A = 25\text{ }^\circ\text{C}$, (see Note 7) | | | 50 | $^\circ\text{C}/\text{W}$ |

NOTE 7: EIA/JESD51-2 environment and PCB has standard footprint dimensions connected with 5 A rated printed wiring track widths.

Parameter Measurement Information

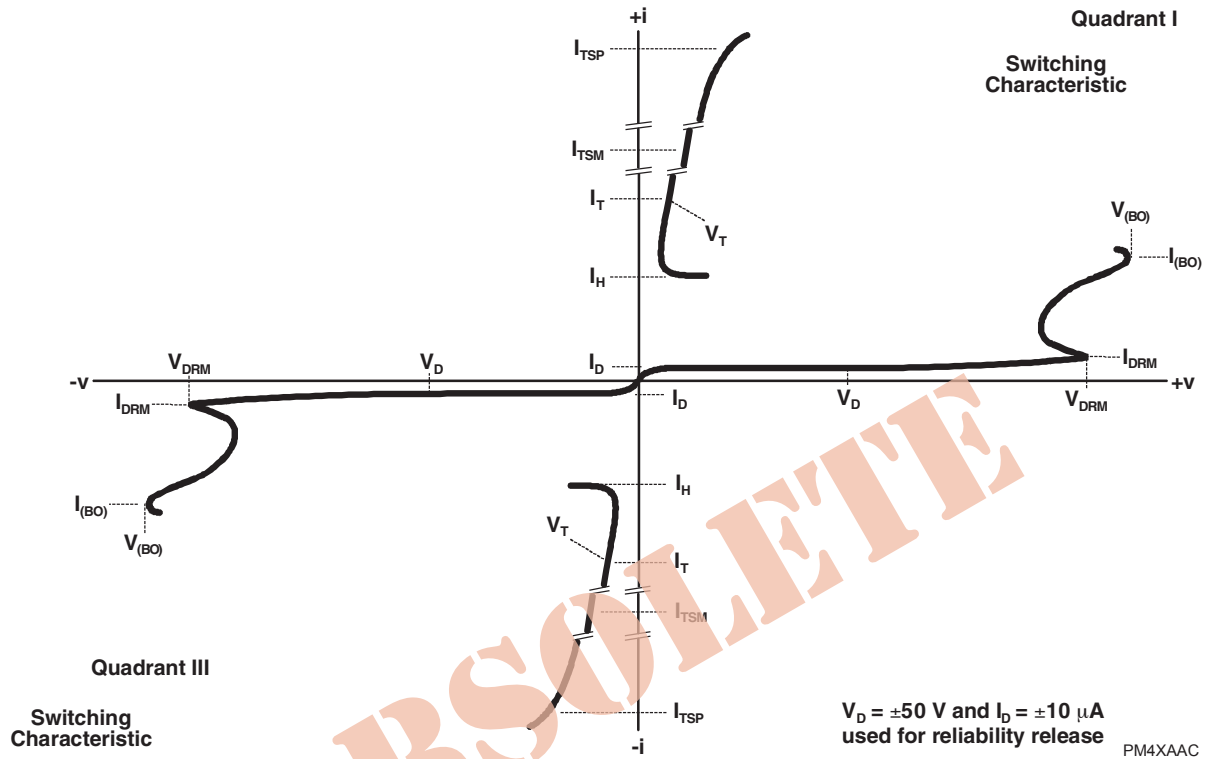


Figure 1. Voltage-current Characteristic for Terminal Pairs

Typical Characteristics

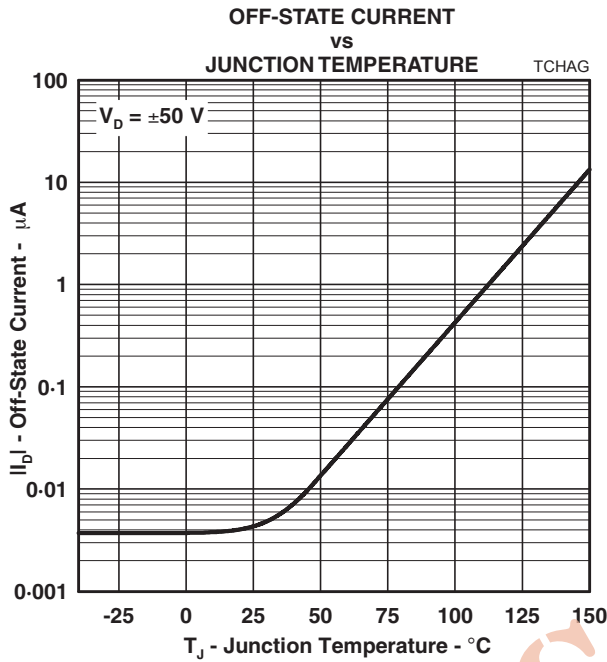


Figure 2.

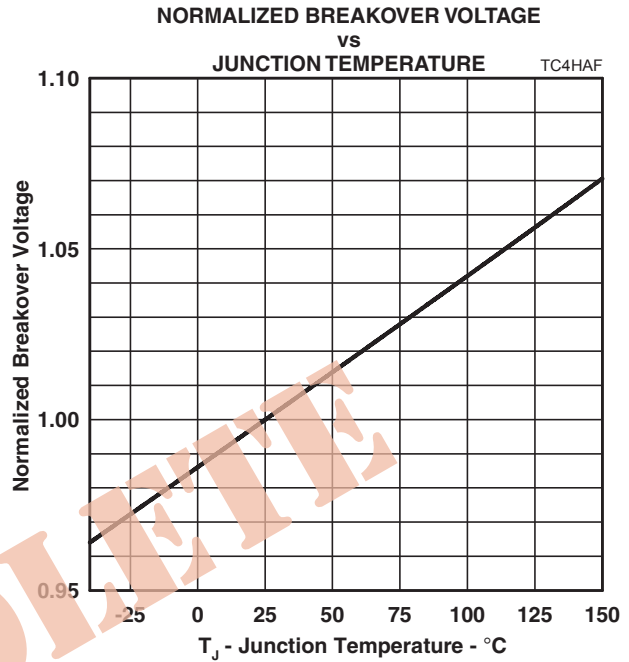


Figure 3.

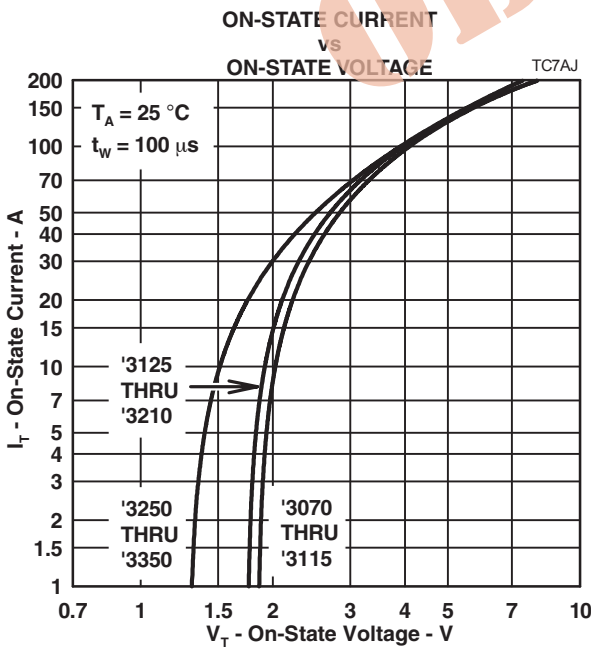


Figure 4.

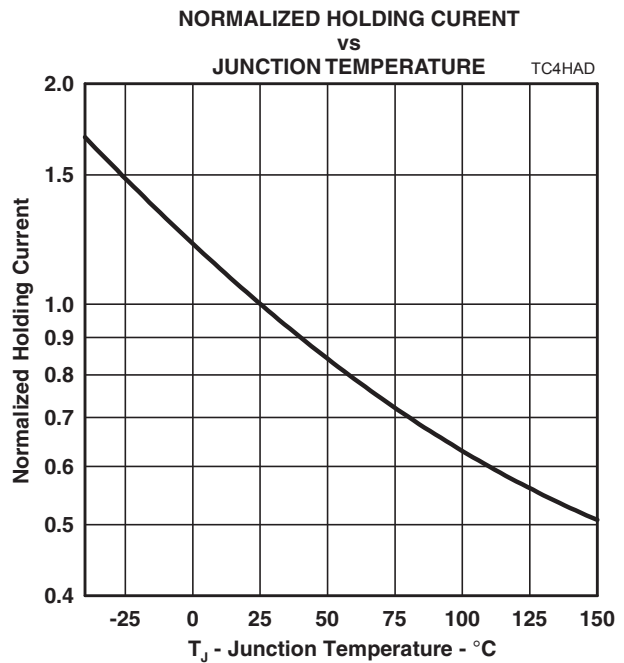


Figure 5.

Typical Characteristics

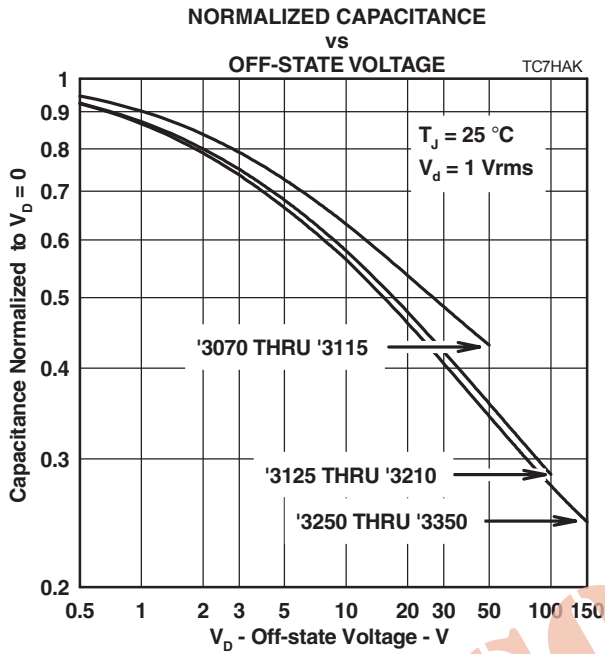


Figure 6.

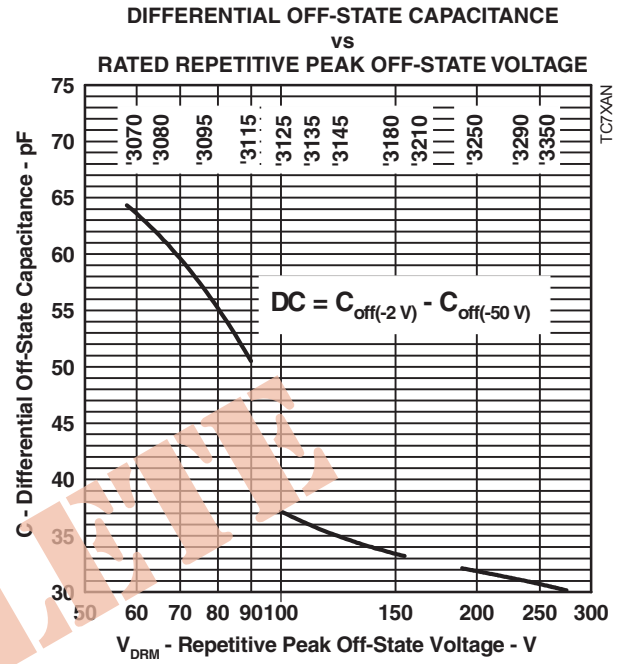


Figure 7.

Typical Characteristics

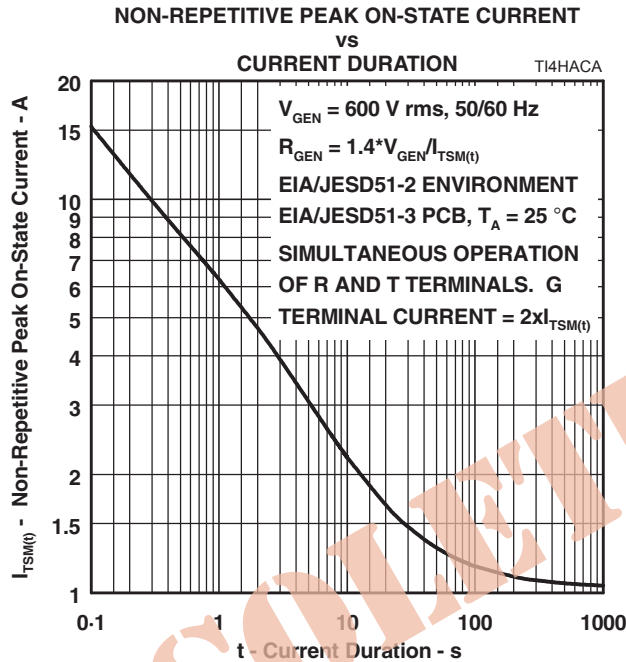


Figure 8.

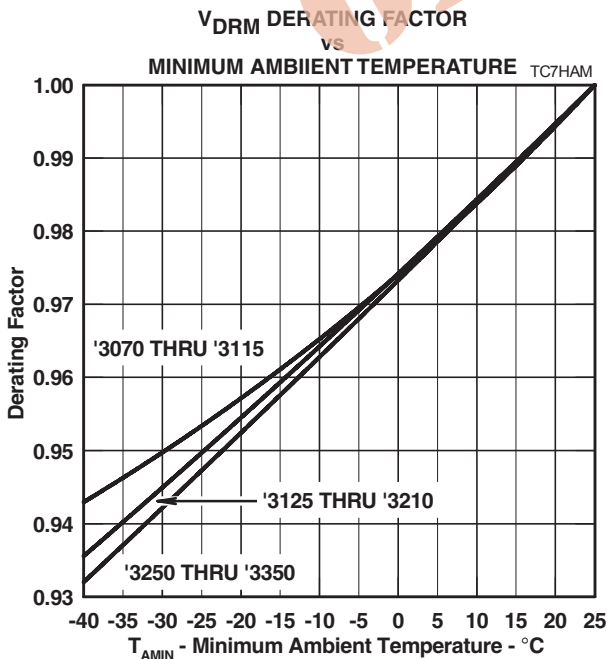


Figure 9.

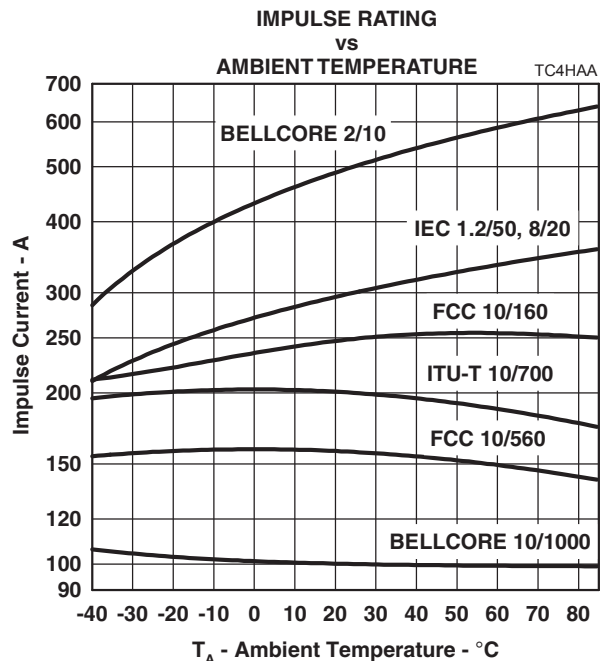


Figure 10.

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 Specifications are subject to change without notice.
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APPLICATIONS INFORMATION

Impulse Testing

To verify the withstand capability and safety of the equipment, standards require that the equipment is tested with various impulse wave forms. The table below shows some common values.

| Standard | Peak Voltage Setting V | Voltage Waveform μs | Peak Current Value A | Current Waveform μs | TISP3xxxH3 25 °C Rating A | Series Resistance Ω |
|-----------------------------|---------------------------|-----------------------------------|-------------------------|-----------------------------------|---------------------------------|-------------------------------|
| GR-1089-CORE | 2500 | 2/10 | 500 | 2/10 | 500 | 0 |
| | 1000 | 10/1000 | 100 | 10/1000 | 100 | |
| FCC Part 68 (March 1998) | 1500 | 10/160 | 200 | 10/160 | 250 | 0 |
| | 800 | 10/560 | 100 | 10/560 | 160 | 0 |
| | 1500 | 9/720 † | 37.5 | 5/320 † | 200 | 0 |
| | 1000 | 9/720 † | 25 | 5/320 † | 200 | 0 |
| I3124 | 1500 | 0.5/700 | 37.5 | 0.2/310 | 200 | 0 |
| ITU-T K.20/K.21 | 1500 | 10/700 | 37.5 | 5/310 | 200 | 0 |
| | 4000 | | 100 | | | |

† FCC Part 68 terminology for the waveforms produced by the ITU-T recommendation K.21 10/700 impulse generator

If the impulse generator current exceeds the protector's current rating, then a series resistance can be used to reduce the current to the protector's rated value to prevent possible failure. The required value of series resistance for a given waveform is given by the following calculations. First, the minimum total circuit impedance is found by dividing the impulse generator's peak voltage by the protector's rated current. The impulse generator's fictitious impedance (generator's peak voltage divided by peak short circuit current) is then subtracted from the minimum total circuit impedance to give the required value of series resistance. In some cases, the equipment will require verification over a temperature range. By using the rated waveform values from Figure 10, the appropriate series resistor value can be calculated for ambient temperatures in the range of -40 °C to 85 °C.

AC Power Testing

The protector can withstand the G return currents applied for times not exceeding those shown in Figure 8. Currents that exceed these times must be terminated or reduced to avoid protector failure. Fuses, PTC (Positive Temperature Coefficient) resistors and fusible resistors are overcurrent protection devices which can be used to reduce the current flow. Protective fuses may range from a few hundred milliamperes to one ampere. In some cases, it may be necessary to add some extra series resistance to prevent the fuse opening during impulse testing. The current versus time characteristic of the overcurrent protector must be below the line shown in Figure 8. In some cases, there may be a further time limit imposed by the test standard (e.g. UL 1459 wiring simulator failure).

Capacitance

The protector characteristic off-state capacitance values are given for d.c. bias voltage, V_D , values of 0, -1 V, -2 V, and -50 V. Where possible, values are also given for -100 V. Values for other voltages may be calculated by multiplying the $V_D = 0$ capacitance value by the factor given in Figure 6. Up to 10 MHz, the capacitance is essentially independent of frequency. Above 10 MHz, the effective capacitance is strongly dependent on connection inductance. In many applications, the typical conductor bias voltages will be about -2 V and -50 V. Figure 7 shows the differential (line unbalance) capacitance caused by biasing one protector at -2 V and the other at -50 V.

Normal System Voltage Levels

The protector should not clip or limit the voltages that occur in normal system operation. For unusual conditions, such as ringing without the line connected, some degree of clipping is permissible. Under this condition, about 10 V of clipping is normally possible without activating the ring trip circuit. Figure 9 allows the calculation of the protector V_{DRM} value at temperatures below 25 °C. The calculated value should not be less than the maximum normal system voltages. The TISP3290H3, with a V_{DRM} of 220 V, can be used for the protection of ring generators producing 105 V rms of ring on a battery voltage of -58 V. The peak ring voltage will be $58 + 1.414 \times 105 = 206.5$ V. However, this is the open circuit voltage and the connection of the line and its equipment will reduce the peak voltage.

APPLICATIONS INFORMATION

Normal System Voltage Levels (continued)

For the extreme case of an unconnected line, the temperature at which clipping begins can be calculated using the data from Figure 9. To possibly clip, the V_{DRM} value has to be 206.5 V. This is a reduction of the 220 V 25 °C V_{DRM} value by a factor of $206.5/220 = 0.94$. Figure 9 shows that a 0.94 reduction will occur at an ambient temperature of -32 °C. In this example, the TISP3290H3 will allow normal equipment operation, even on an open-circuit line, provided that the minimum expected ambient temperature does not fall below -32 °C.

JESD51 Thermal Measurement Method

To standardize thermal measurements, the EIA (Electronic Industries Alliance) has created the JESD51 standard. Part 2 of the standard (JESD51-2, 1995) describes the test environment. This is a 0.0283 m³ (1 ft³) cube which contains the test PCB (Printed Circuit Board) horizontally mounted at the center. Part 3 of the standard (JESD51-3, 1996) defines two test PCBs for surface mount components; one for packages smaller than 27 mm (1.06 ") on a side and the other for packages up to 48 mm (1.89 "). The thermal measurements used the smaller 76.2 mm x 114.3 mm (3.0 " x 4.5 ") PCB. The JESD51-3 PCBs are designed to have low effective thermal conductivity (high thermal resistance) and represent a worse case condition. The PCBs used in the majority of applications will achieve lower values of thermal resistance and so can dissipate higher power levels than indicated by the JESD51 values.

OBSOLETE